Supplementary information

Beta-Fe₂O₃ nanoparticle-assembled film for photoelectrochemical

water splitting

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Figure S1. The theoretical value of saturated photocurrent and solar to hydrogen conversion efficiency (STH) calculate by integrating standard solar spectrum AM1.5G (NASA 2013).



Figure S2. Differential thermal analysis of beta iron oxide nanopowder.



Figure S3. The grain size of β -Fe₂O₃ nanopowder and photoanode annealed at different temperature. Debye-Scherrer formula: $D = K\gamma/Bcos\theta$ was used to calculate the average grain size of two grain orientations (211) and (222).



Figure S4. UV-vis diffuse reflection spectra and band gap obtained by Tauc plot of beta-Fe₂O₃ photoanode annealed at different temperature. The sample annealed at 650°C for 1hour contains a small amount of α -Fe₂O₃, exhibit the properties of direct band gap semiconductor. The sample annealed at 650°C for 32hours pure α -Fe₂O₃, exhibit the properties of indirect band gap semiconductor.



Figure S5. Photocurrent density of photoanode after heat treatment with different annealing temperature. Light source is solar AAA(Newport) and use 1mol/L NaOH as electrolyte.



Figure S6. The schematic diagram of energy band. Band edges of α -Fe₂O₃ and β -Fe₂O₃ are obtained by GGA+U method via VASP package. fermi level and band edges are revised with the 1s orbit core states of the off-defect oxygen ions.



Figure S7. The I-t curve of β -Fe₂O₃ photoanode annealed at 600°C for 1h. Light source is solar AAA(Newport) and use 1mol/L NaOH as electrolyte.



Figure S8. The rietveld refinement of XRD pattern of β -Fe₂O₃ annealed at 650°C for 1h. The content of alpha- Fe₂O₃ is 10.2%(α : $\beta \approx$ 1:9)and the error factor R=7.84%.